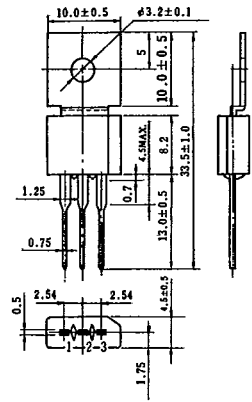


**MAXIMUM RATINGS**

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SF2B41 SF2D41 SF2G41 SF2J41	$V_{DRM}$ and $V_{RRM}$	100 200 400 600	V
Non-Repetitive Peak Reverse Voltage (Non-Rep <5ms) $T_c=0\sim 110^\circ\text{C}$	SF2B41 SF2D41 SF2G41 SF2J41	$V_{RSM}$	150 300 500 720	V
R.M.S On-State Current	$I_T(RMS)$	3.1	A	
Average On-State Current (Half Sine Waveform $T_c=45^\circ\text{C}$ )	$I_T(AV)$	2.0	A	
Peak One Cycle Surge On-State Current (Non-Repetitive)	$I_{TSM}$	22(60Hz) 20(50Hz)	A	
$I^2t$ Limit Value ( $t=1\text{ms}\sim 10\text{ms}$ )	$I^2t$	1.6	$\text{A}^2\text{S}$	
Peak Gate Power Dissipation	$P_{GM}$	0.1	W	
Average Gate Power Dissipation	$P_{G(AV)}$	0.01	W	
Peak Forward Gate Voltage	$I_{GM}$	100	mA	
Peak Reverse Gate Voltage	$V_{RGM}$	-5	V	
Junction Temperature	$T_j$	-40~110	$^\circ\text{C}$	
Storage Temperature Range	$T_{stg}$	-40~110	$^\circ\text{C}$	
Weight		1.5	g	



1. CATHODE
2. ANODE
3. GATE

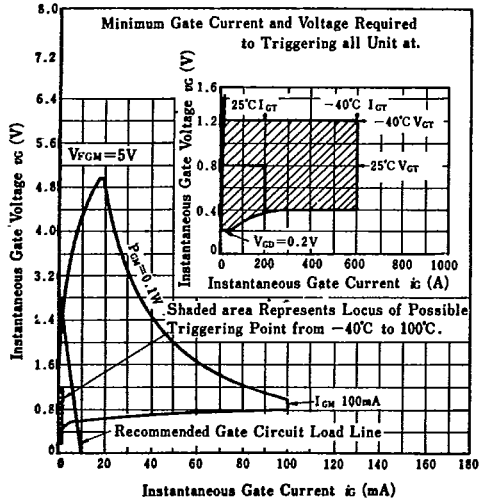
JEDEC	-
EIAJ	-
TOSHIBA	13-10A1A

**ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	$I_{DRM}$ and $I_{RRM}$	$V_{DRM}=V_{RRM}=\text{Rated}$ $T_j=110^\circ\text{C}$ , $R_{GK}=1\text{k}\Omega$	-	-	200	$\mu\text{A}$
Peak On-State Voltage	$V_{TM}$	$I_{TM}=10\text{A}$ , $T_c=25^\circ\text{C}$	-	-	2.0	V
Gate Trigger Voltage	$V_{GT}$	$V_D=6\text{V}$ , $R_L=100\Omega$ , $R_{GK}=1\text{k}\Omega$ , $T_c=25^\circ\text{C}$	-	-	0.8	V
Gate Trigger Current	$I_{GT}$	$V_D=6\text{V}$ , $R_L=100\Omega$ , $R_{GK}=1\text{k}\Omega$ , $T_c=25^\circ\text{C}$	-	-	200	$\mu\text{A}$
Gate Non-Trigger Voltage	$V_{GD}$	$V_D=\text{Rated}$ , $R_{GK}=1\text{k}\Omega$ , $T_c=110^\circ\text{C}$	0.2	-	-	V
Critical Rate of Rise of Off-State Voltage	$dv/dt$	$V_{DRM}=\text{Rated}$ , $R_{GK}=1\text{k}\Omega$ Exponential rise $T_j=110^\circ\text{C}$	-	15 *10	-	$\text{V}/\mu\text{s}$
Holding Current	$I_H$	$R_L=100\Omega$ , $R_{GK}=1\text{k}\Omega$ , $T_c=25^\circ\text{C}$	-	3.0	-	mA
Thermal Resistance *	$R_{th(j-c)}$	DC	-	-	12	$^\circ\text{C}/\text{W}$

\* Junction to Case      \* SF2J41

**GATE TRIGGERING CHARACTERISTICS**



**$T_c \text{ MAX} - I_T(AV)$**

